

BEST AVAILABLE COPY
FEB 17 2005

Practitioner's Docket No.: TSL-124

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Micha Gutman et al.
Assignee: Tower Semiconductor Ltd.
Serial No.: 10/659,042
Filed: 9/9/2003
For: "METHOD OF DECREASING CHARGING EFFECTS
IN OXIDE-NITRIDE-OXIDE (ONO) ARRAYS"

Art Unit.: 2812
Examiner: Walter Lee Lindsay, Jr.

February 17, 2005

VIA FACSIMILE (703) 872-9306

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO RESTRICTION REQUIREMENT

Sir:

In response to the outstanding Office Action dated February 4, 2005, in which the Examiner imposed a restriction requirement to election of invention for the above-referenced application, Applicants elect to prosecute the invention as in Group II, Claims 7-21 drawn to a method of forming a fieldless array, without traverse.

Applicants reserve the right to file divisional applications on the non-elected claims.

Respectfully submitted,



E. Eric Hoffman,
Reg. No. 38,186
Attorney for Applicants

Customer No.: 022888
Tel. No.: (925) 895-3545
Fax No.: (925) 371-8187

CERTIFICATE OF TRANSMISSION (37 C.F.R. 1.8(a))

I hereby certify that, on the date shown below, this correspondence is being transmitted by facsimile to the Patent and Trademark Office.

Date: 2/17/05 Signature: Carrie Reddick
Carrie Reddick